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NTE ELECTRONICS, INC.
44 FARRAND STREET
BLOOMFIELD, NJ 07003
(973) 748–5089

NTE1840 & NTE1841
Integrated Circuit
Hybrid Switching Voltage Regulator

Features:
- Triple Diffused Transistor Chips Incorporated
- Compact Plastic Package with Industry Standard Reliability
- Output Voltage is Pre–Fixed – No External Adjustment is Required

Absolute Maximum Ratings:

Peak Input Voltage, V_{IN} 550V
Input Current, I_{IN}
Continuous 6A
Pulse 12A
Power Dissipation (T_C = +100°C), P_D 27W
Maximum Power Transistor Junction Temperature, T_J . . . . . +150°C
Operating Temperature Range (T_C), T_{opr} . . . . . –20° to +125°C
Storage Temperature Range, T_{stg} . . . . . –30° to +125°C

Electrical Characteristics: (T_A = +25°C unles otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Output Voltage	V_O	V_{IN} = 120V, I_O = 900mA	114.5	116.0	117.5	V
Detecting Voltage (Fixed Output) NTE1840	V_O	I_{in} = 7mA	41.3	41.8	42.3	V
NTE1841			42.5	43.0	43.5	V
Load Regulation	Reg_{LOAD}	V_{IN} = 120V, I_O = 500mA to 900mA	Initial Value ±1			V
Output Voltage Temperature Coefficient		T_C = –20° to +100°C, I_{in} = 7mA	–	±2	–	mV/°C
Saturation Voltage	$V_{CE(sat)}$	I_C = 2A, I_B = 400mA	–	–	1.0	V
	$V_{BE(sat)}$	I_C = 2A, I_B = 400mA	–	–	1.5	V
DC Current Gain	h_{FE}	I_C = 1A, V_{CE} = 4V	10	–	40	
Collector Cutoff Current	I_{CEX}	V_{CE} = 550V, V_{BE} = –1.5V	–	–	1.0	mA
Power Transistor Thermal Resistance	R_{thJC}	Between Junction and Stem Upper Surface	–	1.8	–	°C/W
Switching Time	t_s	I_C = 2A, I_{B1} = 300mA, I_{B2} = 300mA, R_L = 50Ω	–	–	12	µs
	t_f		–	–	7	µs

Note 1. Recommended Case Temperature: T_{opr} = +100°C.

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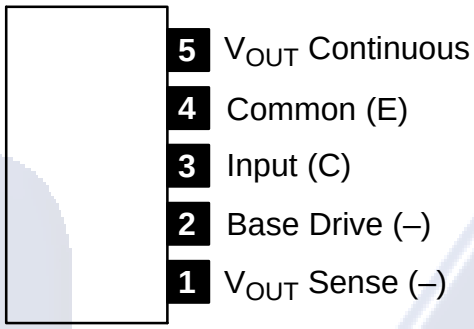
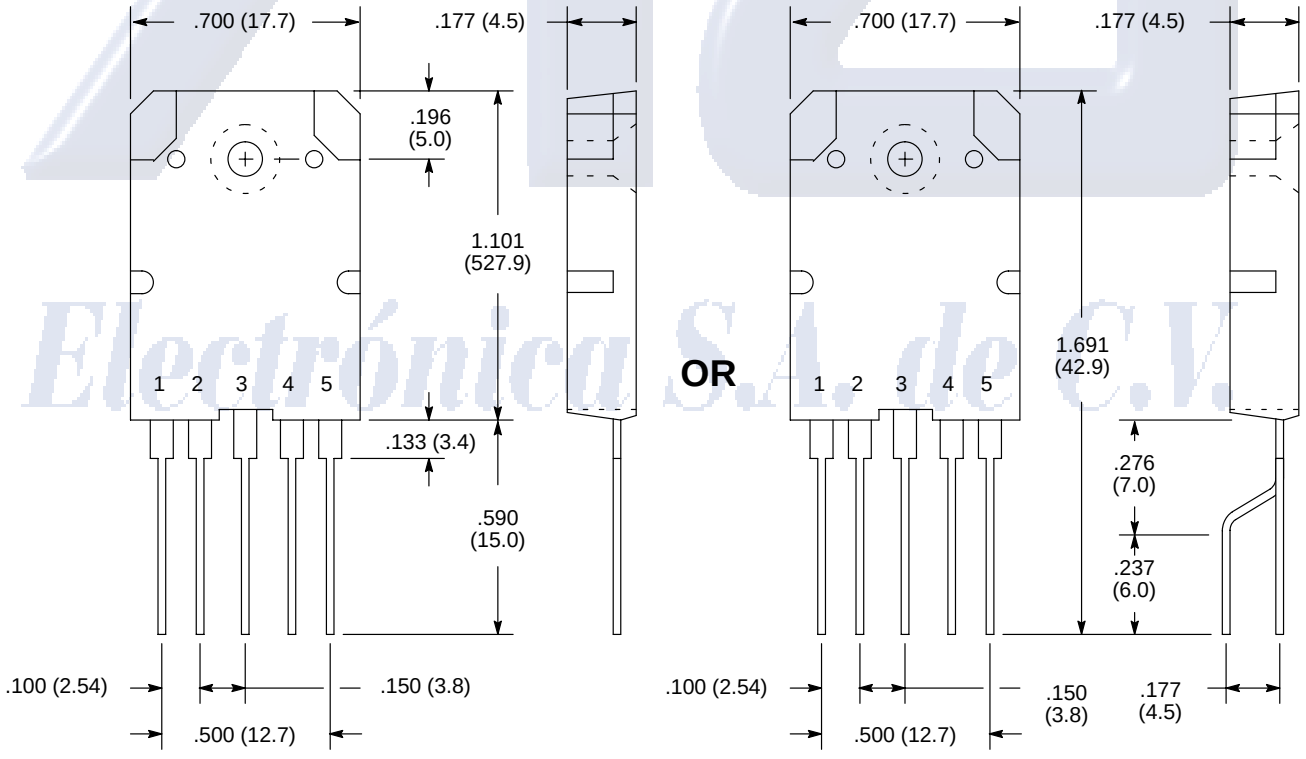
Pin Connection Diagram
(Front View)





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